ESD Protection Diode Array, 5-Line

This 5-line surge protection array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as computers, printers, automotive electronics, networking communication and other applications. This device features a monolithic common anode design which protects five independent lines in a single SC-88 package.

Features

- Protects up to 5-Line in a Single SC-88 Package
- Peak Power Dissipation 100 W (8 x 20 µs Waveform)
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model.
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8 kV (Contact)
- Flammability Rating of UL 94 V-0
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- Pb-Free Packages are Available*

Applications

- Hand-Held Portable Applications
- Networking and Telecom
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

MAXIMUM RATINGS (T_J = 25°C unless otherwise specified)

Symbol	Rating	Value	Unit
P _{PK} 1	Peak Power Dissipation 8 x 20 μs Double Exponential Waveform (Note 1)	100	W
TJ	Operating Junction Temperature Range	-40 to 125	°C
T _{STG}	Storage Temperature Range	-55 to 150	°C
T _L	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	16000 400 15000 15000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



ON Semiconductor®

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SC-88 FIVE SURGE PROTECTION 100 W PEAK POWER



SC-88 CASE 419B STYLE 24

PIN ASSIGNMENT



- PIN1. CATHODE
 - 2. ANODE
 - 3. CATHODE
 - 4. CATHODE
 - 5. CATHODE
 - 6. CATHODE

MARKING DIAGRAM



XX = Specific Device Code

6J = SMF05C

6K = SZSMF12C/SMF12C

6L = SMF15C

6M = SMF24C

M = Date Code= Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

1

^{1.} Nonrepetitive current pulse per Figure 3.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SMF05CT1G ELECTRICAL CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			5.0	V
Breakdown Voltage	V _{BR}	I _T = 1 mA, (Note 3)	6.2		7.2	V
Reverse Leakage Current	I _R	V _{RWM} = 5 V		0.07	5.0	μΑ
Clamping Voltage	V _C	I _{PP} = 5 A (8 x 20 μs Waveform)			9.8	V
Clamping Voltage	V _C	I _{PP} = 8 A (8 x 20 μs Waveform)			12.5	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			8.0	Α
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		80	130	pF

SMF12CT1G ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			12	٧
Breakdown Voltage	V_{BR}	I _T = 1 mA, (Note 3)	13.3		15	٧
Reverse Leakage Current	I _R	V _{RWM} = 12 V		0.01	0.1	μΑ
Clamping Voltage	V _C	I _{PP} = 3 A (8 x 20 μs Waveform)			21	V
Clamping Voltage	V _C	I _{PP} = 6 A (8 x 20 μs Waveform)			23	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			6.0	Α
Capacitance	СЈ	V _R = 0 V, f = 1 MHz (Line to GND)		40	60	pF

$\textbf{SMF15CT1G ELECTRICAL CHARACTERISTICS} \ (T_J = 25^{\circ}C, \ unless \ otherwise \ specified)$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			15	V
Breakdown Voltage	V_{BR}	I _T = 1 mA, (Note 3)	17		19	V
Reverse Leakage Current	I _R	V _{RWM} = 15 V		0.01	1.0	μΑ
Clamping Voltage	V _C	I _{PP} = 1 A (8 x 20 μs Waveform)			23	V
Clamping Voltage	V _C	I _{PP} = 5 A (8 x 20 μs Waveform)			29	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			5.0	Α
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		33	45	pF

SMF24CT1G ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			24	V
Breakdown Voltage	V_{BR}	I _T = 1 mA, (Note 3)	26.7		32	V
Reverse Leakage Current	I _R	V _{RWM} = 24 V		0.01	1.0	μА
Clamping Voltage	V _C	I _{PP} = 1 A (8 x 20 μs Waveform)			40	V
Clamping Voltage	V _C	I _{PP} = 2.5 A (8 x 20 μs Waveform)			44	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			2.5	Α
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		21	25	pF

^{2.} Surge protection devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.

3. V_{BR} is measured at pulse test current I_T.

^{4.} Include SZ-prefix devices where applicable.

TYPICAL PERFORMANCE CURVES

(T_J = 25°C unless otherwise specified)

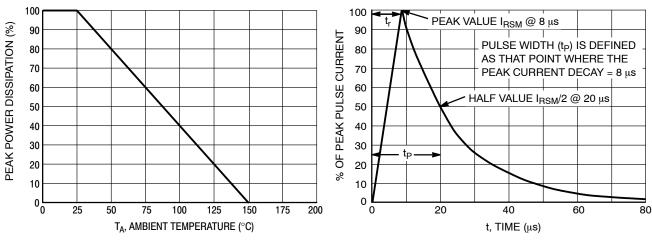


Figure 1. Pulse Derating Curve

Figure 2. $8\times 20~\mu s$ Pulse Waveform

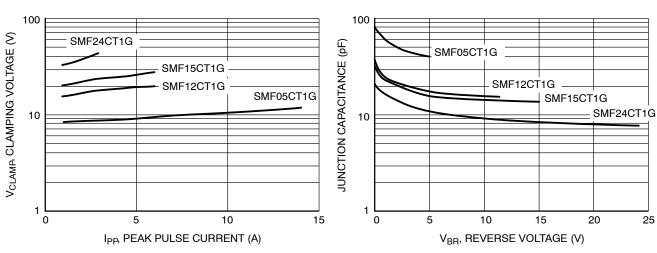


Figure 3. Clamping Voltage vs Peak Pulse Current

Figure 4. Junction Capacitance vs Reverse Voltage

ORDERING INFORMATION

Device	Package	Shipping [†]
SMF05CT1G	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF05CT2G*	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF12CT1G	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF15CT1G	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF24CT1G	SC-88 (Pb-Free)	3,000 / Tape & Reel

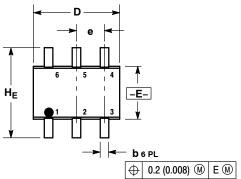
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

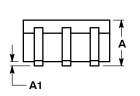
^{*}The "T2" suffix refers to an alternate tape & reel orientation.

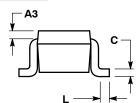
PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363

CASE 419B-02 **ISSUE W**







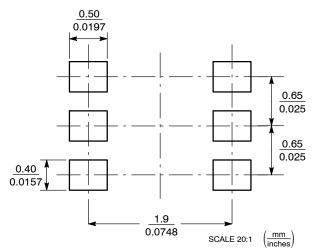
NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

		MIL	LIMETE	ERS	INCHES				
D	MIC	MIN	NOM	MAX	MIN	NOM	MAX		
	Α	0.80	0.95	1.10	0.031	0.037	0.043		
1	41	0.00	0.05	0.10	0.000	0.002	0.004		
1	43		0.20 REF			0.008 REF			
	b	0.10	0.21	0.30	0.004	0.008	0.012		
	С	0.10	0.14	0.25	0.004	0.005	0.010		
	D	1.80	2.00	2.20	0.070	0.078	0.086		
	Е	1.15	1.25	1.35	0.045	0.049	0.053		
	е		0.65 BS	С	0	.026 BS	С		
	L	0.10	0.20	0.30	0.004	0.008	0.012		
F	π	2.00	2.10	2.20	0.078	0.082	0.086		

STYLE 24:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE

SOLDERING FOOTPRINT*



SC-88/SC70-6/SOT-363

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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